

RF LDMOS Wideband Integrated Power Amplifiers

The MW4IC2230 wideband integrated circuit is designed for W-CDMA base station applications. It uses Freescale's newest High Voltage (26 to 28 Volts) LDMOS IC technology and integrates a multi-stage structure. Its wideband On-Chip design makes it usable from 1600 to 2400 MHz. The linearity performances cover all modulations for cellular applications: GSM, GSM EDGE, TDMA, CDMA and W-CDMA.

Final Application

- Typical Single-carrier W-CDMA Performance: $V_{DD} = 28$ Volts, $I_{DQ1} = 60$ mA, $I_{DQ2} = 350$ mA, $P_{out} = 5$ Watts Avg., $f = 2140$ MHz, Channel Bandwidth = 3.84 MHz, Peak/Avg. = 8.5 dB @ 0.01% Probability on CCDF.
 - Power Gain — 31 dB
 - Drain Efficiency — 15%
 - ACPR @ 5 MHz = -45 dBc @ 3.84 MHz Bandwidth

Driver Application

- Typical Single-carrier W-CDMA Performance: $V_{DD} = 28$ Volts, $I_{DQ1} = 60$ mA, $I_{DQ2} = 350$ mA, $P_{out} = 0.4$ Watts Avg., $f = 2140$ MHz, Channel Bandwidth = 3.84 MHz, Peak/Avg. = 8.5 dB @ 0.01% Probability on CCDF.
 - Power Gain — 31.5 dB
 - ACPR @ 5 MHz = -53.5 dBc @ 3.84 MHz Bandwidth
- Capable of Handling 3:1 VSWR, @ 28 Vdc, 2170 MHz, 5 Watts CW Output Power
- Characterized with Series Equivalent Large-Signal Impedance Parameters
- On-Chip Matching (50 Ohm Input, DC Blocked, >5 Ohm Output)
- Integrated Quiescent Current Temperature Compensation with Enable/Disable Function
- On-Chip Current Mirror g_m Reference FET for Self Biasing Application (1)
- Integrated ESD Protection
- N Suffix Indicates Lead-Free Terminations
- 200°C Capable Plastic Package
- Also Available in Gull Wing for Surface Mount
- In Tape and Reel. R1 Suffix = 500 Units per 44 mm, 13 inch Reel

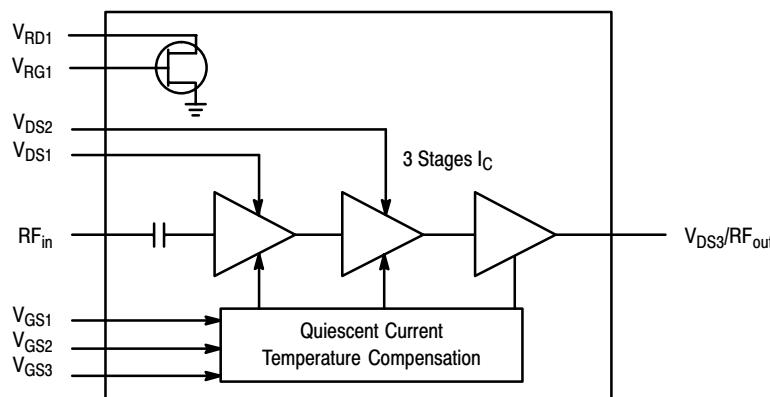
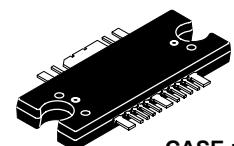


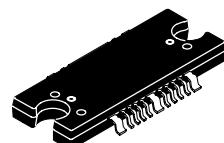
Figure 1. Functional Block Diagram

MW4IC2230NBR1
MW4IC2230GNBR1
MW4IC2230MBR1
MW4IC2230GMBR1

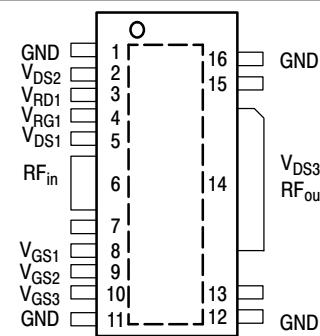
2110-2170 MHz, 30 W, 28 V
SINGLE W-CDMA
RF LDMOS WIDEBAND
INTEGRATED POWER AMPLIFIERS



CASE 1329-09
TO-272 WB-16
PLASTIC
MW4IC2230NBR1(MBR1)



CASE 1329A-03
TO-272 WB-16 GULL
PLASTIC
MW4IC2230GNBR1(GMBR1)



Note: Exposed backside flag is source terminal for transistors.

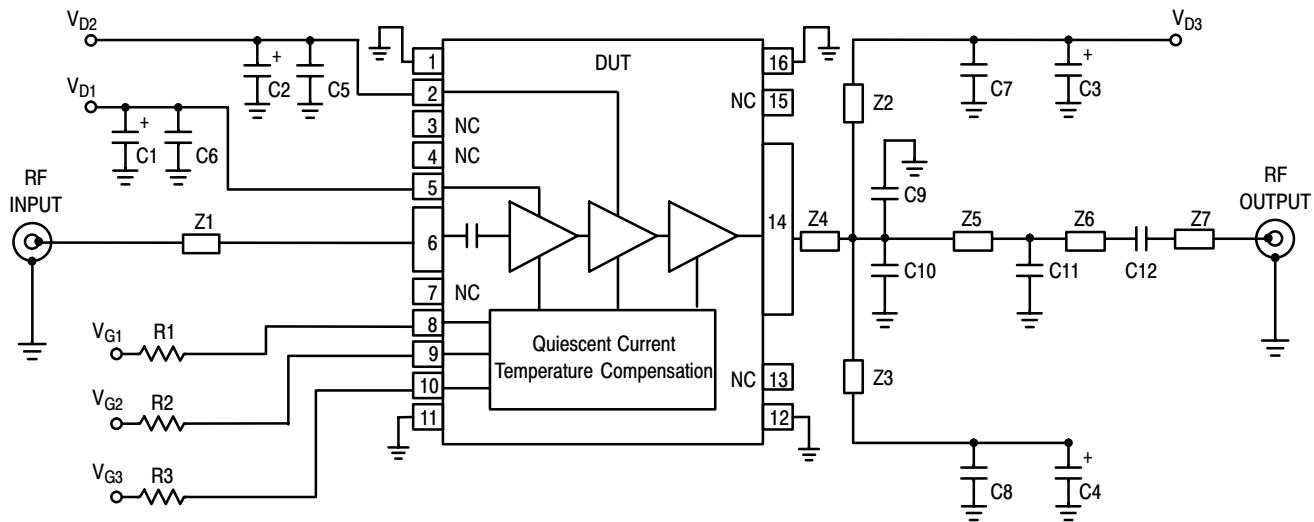
Figure 2. Pin Connections

- Refer to AN1987/D, *Quiescent Current Control for the RF Integrated Circuit Device Family*. Go to <http://www.freescale.com/rf>. Select Documentation/Application Notes - AN1987.

Table 5. Electrical Characteristics ($T_C = 25^\circ\text{C}$ unless otherwise noted) **(continued)**

Characteristic	Symbol	Min	Typ	Max	Unit
Typical Performances (In Freescale Reference Application Circuit tuned for 2-carrier W-CDMA signal) $V_{DD} = 28 \text{ Vdc}$, $P_{out} = 0.4 \text{ W Avg.}$, $I_{DQ1} = 60 \text{ mA}$, $I_{DQ2} = 400 \text{ mA}$, $I_{DQ3} = 245 \text{ mA}$, $f_1 = 2112.5 \text{ MHz}$, $f_2 = 2122.5 \text{ MHz}$ and $f_3 = 2157.5 \text{ MHz}$, $f_4 = 2167.5 \text{ MHz}$, 2-carrier W-CDMA, 3.84 MHz Channel Bandwidth Carriers. ACPR measured in 3.84 MHz Channel Bandwidth @ $\pm 5 \text{ MHz}$ Offset. IM3 measured in 3.84 MHz Channel Bandwidth @ $\pm 10 \text{ MHz}$ Offset. Peak/Avg. = 8.5 dB @ 0.01% Probability on CCDF.					
Power Gain	G_{ps}	—	31.5	—	dB
Intermodulation Distortion	IM3	—	-52	—	dBc
Adjacent Channel Power Ratio	ACPR	—	-55	—	dBc
Input Return Loss	IRL	—	-26	—	dB

NOTE - **CAUTION** - MOS devices are susceptible to damage from electrostatic charge. Reasonable precautions in handling and packaging MOS devices should be observed.



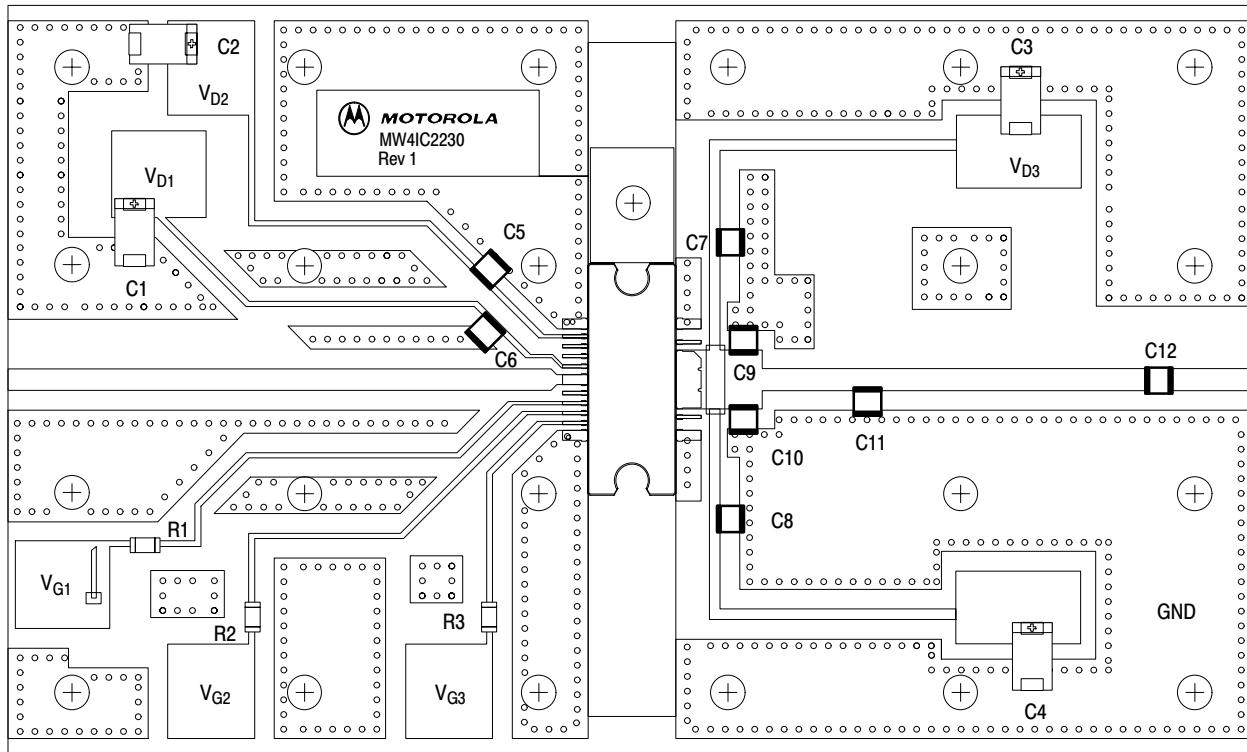
Z1 2.180" x 0.090" Microstrip
 Z2, Z3 0.040" x 0.430" Microstrip
 Z4 0.350" x 0.240" Microstrip
 Z5 0.420" x 0.090" Microstrip

Z6 1.120" x 0.090" Microstrip
 Z7 0.340" x 0.090" Microstrip
 PCB Taconic TLX8-0300, 0.030", $\epsilon_r = 2.55$

Figure 3. MW4IC2230NBR1(MBR1)/GNBR1(GMBR1) Test Circuit Schematic

Table 6. MW4IC2230NBR1(MBR1)/GNBR1(GMBR1) Test Circuit Component Designations and Values

Part	Description	Part Number	Manufacturer
C1, C2, C3, C4	10 μ F, 35 V Tantalum Capacitors	TAJD106K035	AVX
C5, C6, C7, C8, C12	8.2 pF 100B Chip Capacitors	100B8R2CW	ATC
C9, C10	1.8 pF 100B Chip Capacitors	100B1R8BW	ATC
C11	0.3 pF 100B Chip Capacitor	100B0R3BW	ATC
R1, R2, R3	1.8 k Ω Chip Resistors (1206)		



Freescale has begun the transition of marking Printed Circuit Boards (PCBs) with the Freescale Semiconductor signature/logo. PCBs may have either Motorola or Freescale markings during the transition period. These changes will have no impact on form, fit or function of the current product.

Figure 4. MW4IC2230NBR1(MBR1)/GNBR1(GMBR1) Test Circuit Component Layout

TYPICAL CHARACTERISTICS

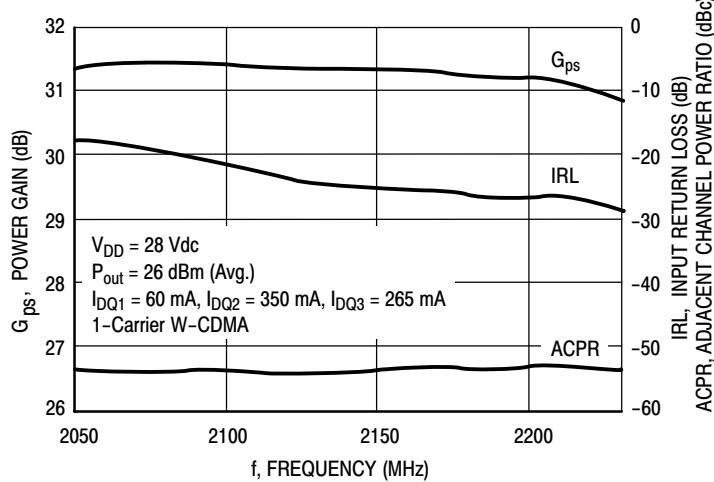


Figure 5. Single-Carrier W-CDMA Wideband Performance @ $P_{out} = 26$ dBm

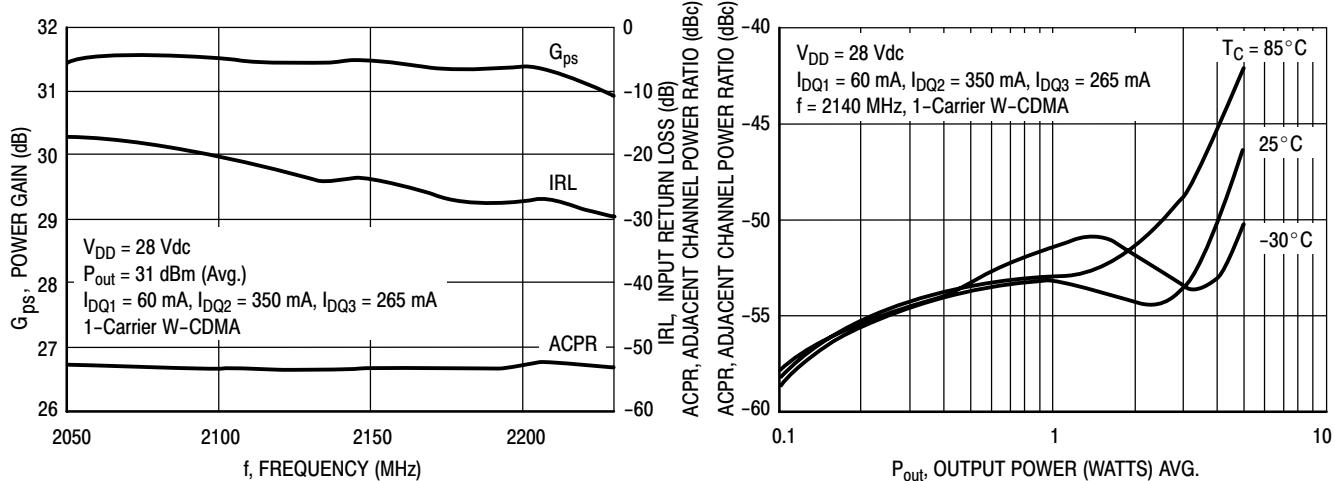


Figure 6. Single-Carrier W-CDMA Wideband Performance @ $P_{out} = 31$ dBm

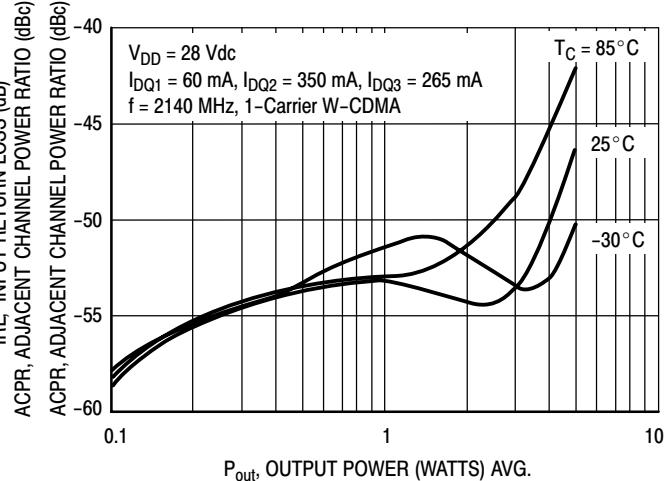


Figure 7. Adjacent Channel Power Ratio versus Output Power

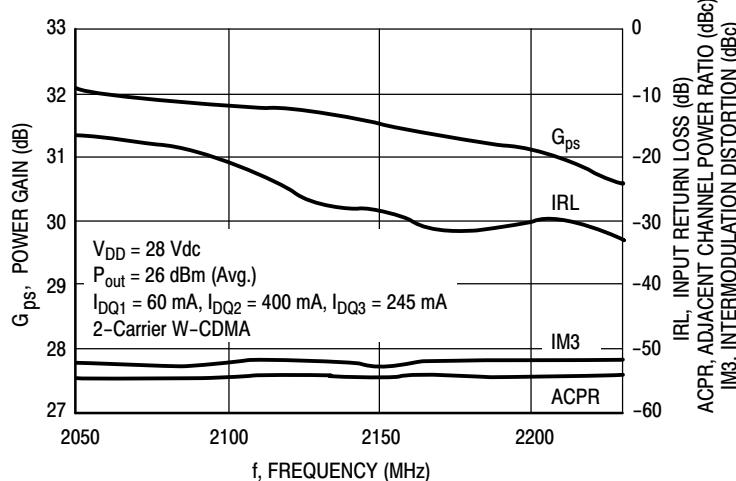


Figure 8. 2-Carrier W-CDMA Wideband Performance

TYPICAL CHARACTERISTICS

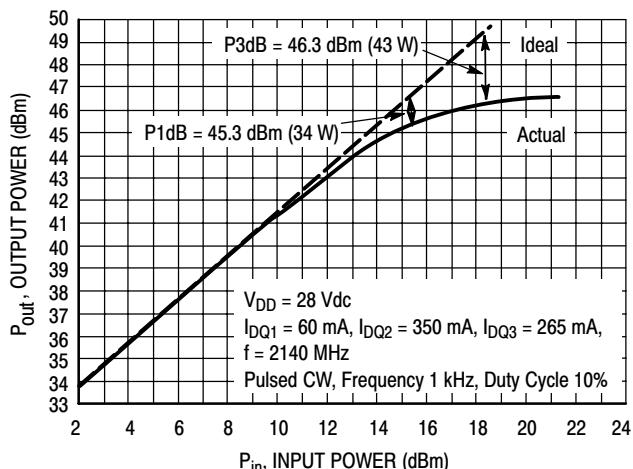


Figure 9. Output Power versus Input Power

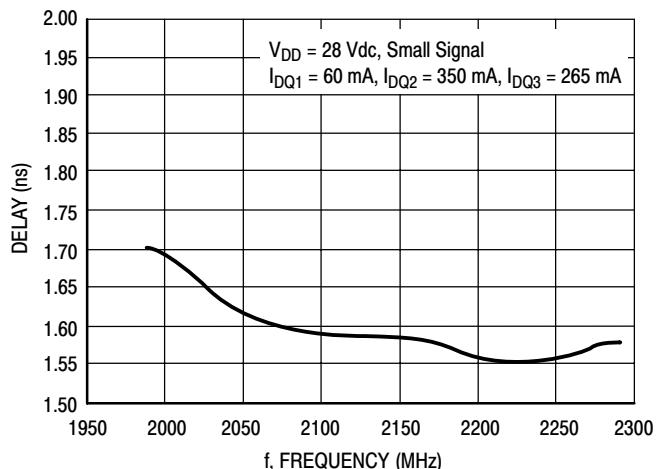
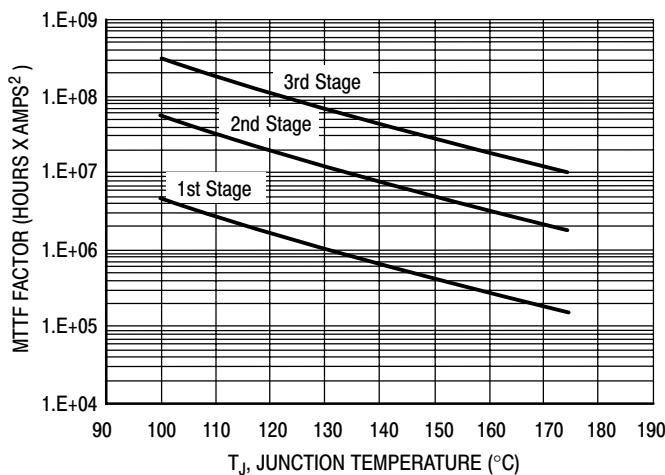
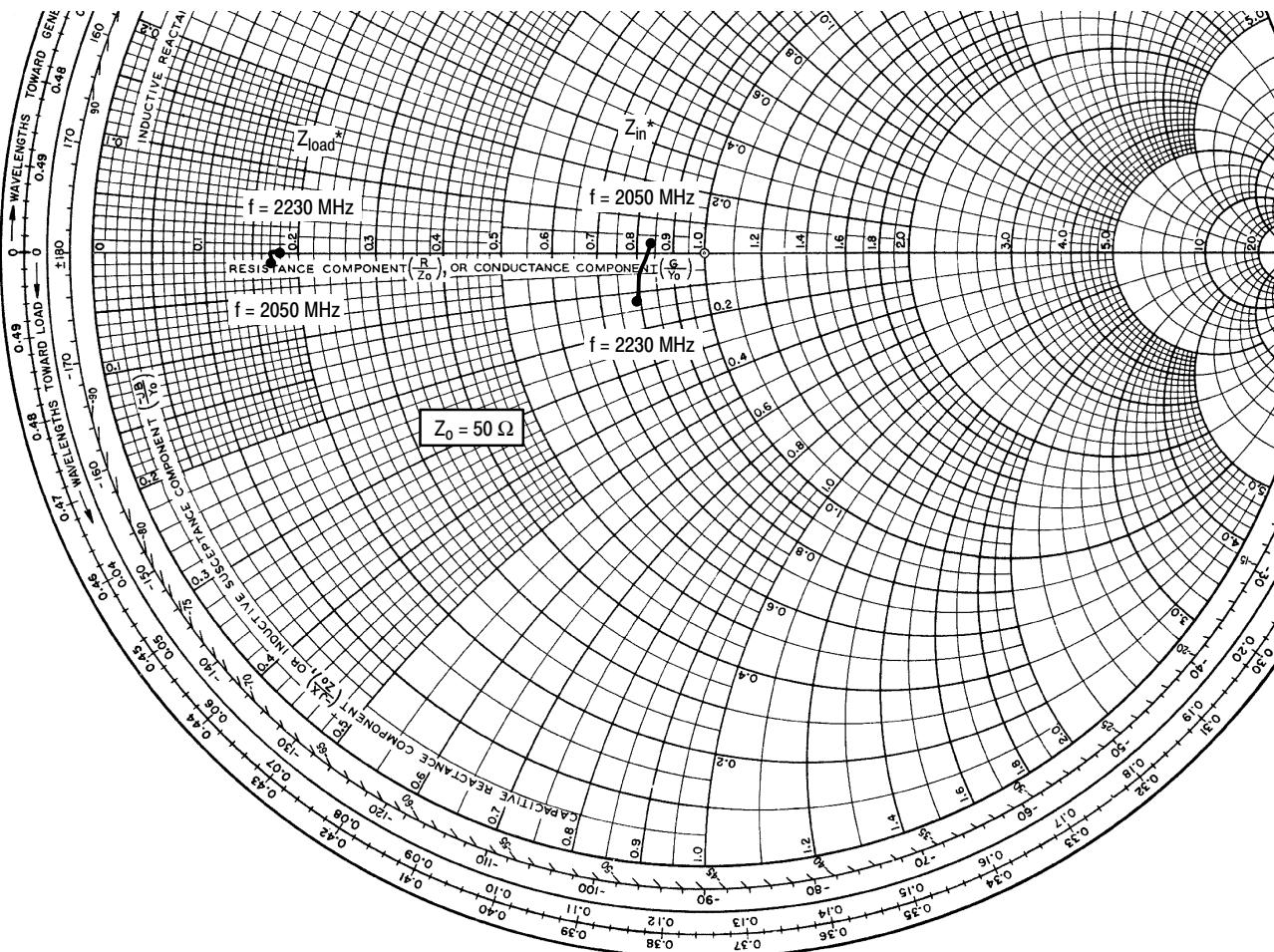


Figure 10. Delay versus Frequency



This above graph displays calculated MTTF in hours x ampere² drain current. Life tests at elevated temperatures have correlated to better than $\pm 10\%$ of the theoretical prediction for metal failure. Divide MTTF factor by I_D² for MTTF in a particular application.

Figure 11. MTTF Factor versus Temperature Junction



$V_{DD} = 28$ V, $I_{DQ1} = 60$ mA, $I_{DQ2} = 350$ mA, $I_{DQ3} = 265$ mA, $P_{out} = 26$ dBm

f MHz	Z_{in} Ω	Z_{load} Ω
2050	$42.18 + j1.49$	$8.52 - j0.46$
2110	$41.06 - j1.30$	$8.58 - j0.20$
2140	$40.49 - j2.42$	$8.63 - j0.09$
2170	$40.05 - j3.45$	$8.69 - j0.01$
2230	$39.29 - j6.31$	$8.81 + j0.04$

Z_{in} = Device input impedance as measured from gate to ground.

Z_{load} = Test circuit impedance as measured from drain to ground.

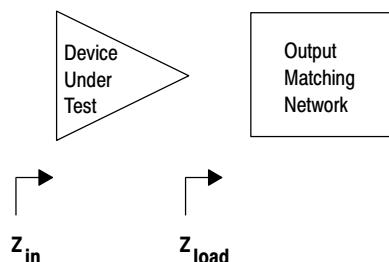


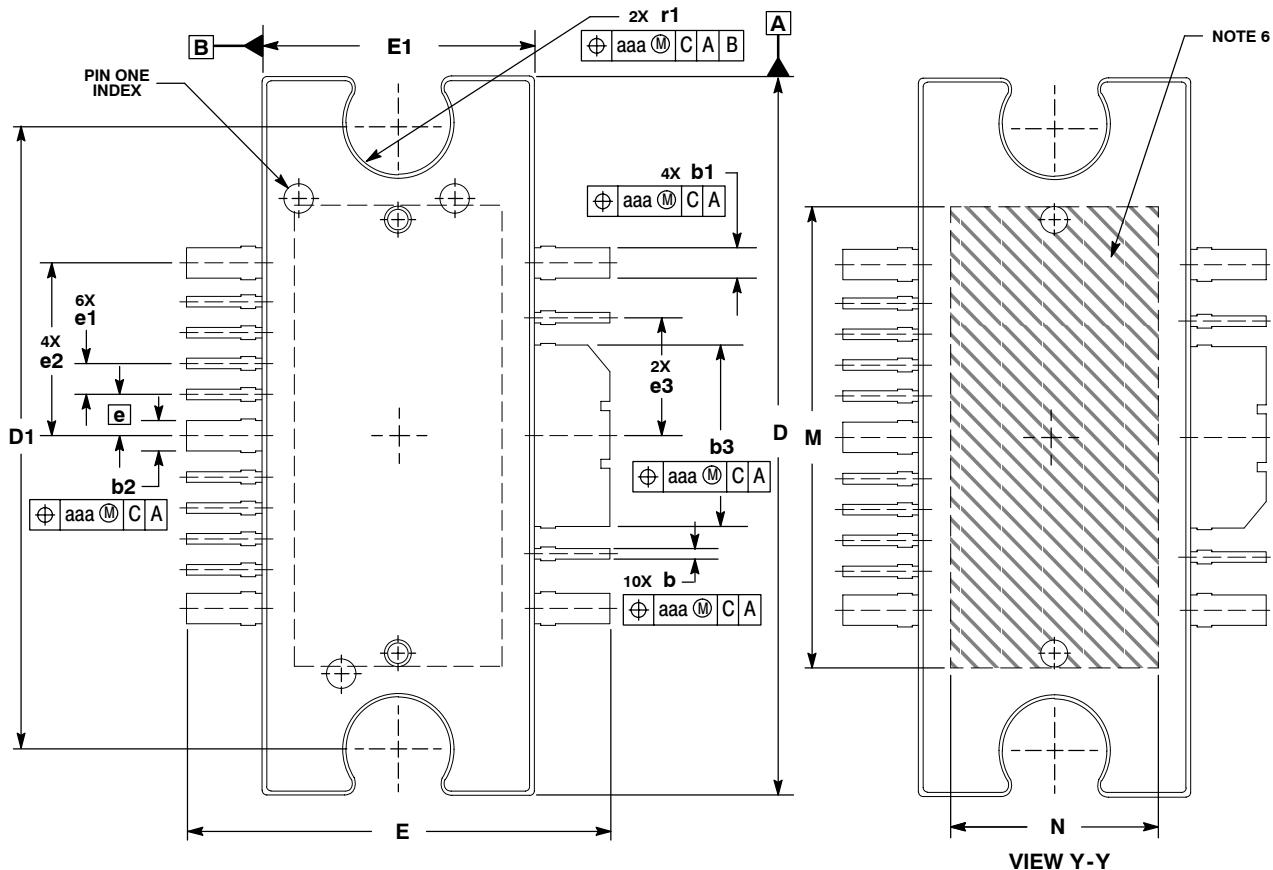
Figure 12. Series Equivalent Input and Load Impedance

MW4IC2230NBR1 MW4IC2230GNBR1 MW4IC2230MBR1 MW4IC2230GMBR1

NOTES

MW4IC2230NBR1 MW4IC2230GNBR1 MW4IC2230MBR1 MW4IC2230GMBR1

PACKAGE DIMENSIONS



NOTES:

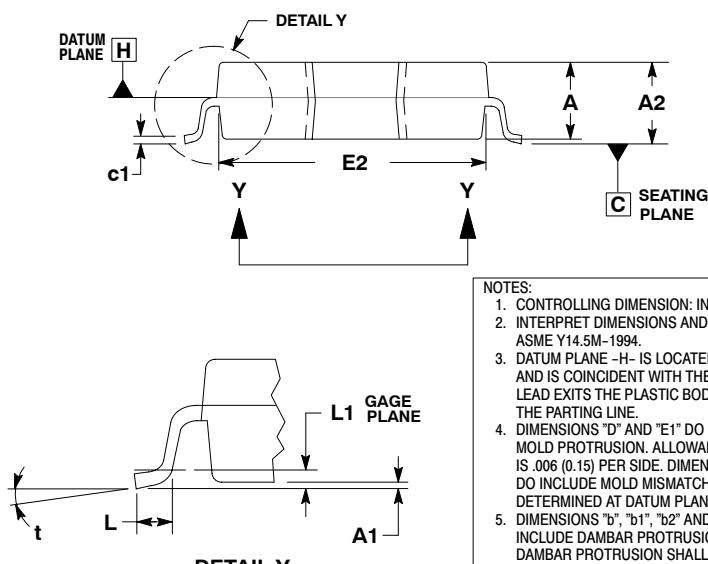
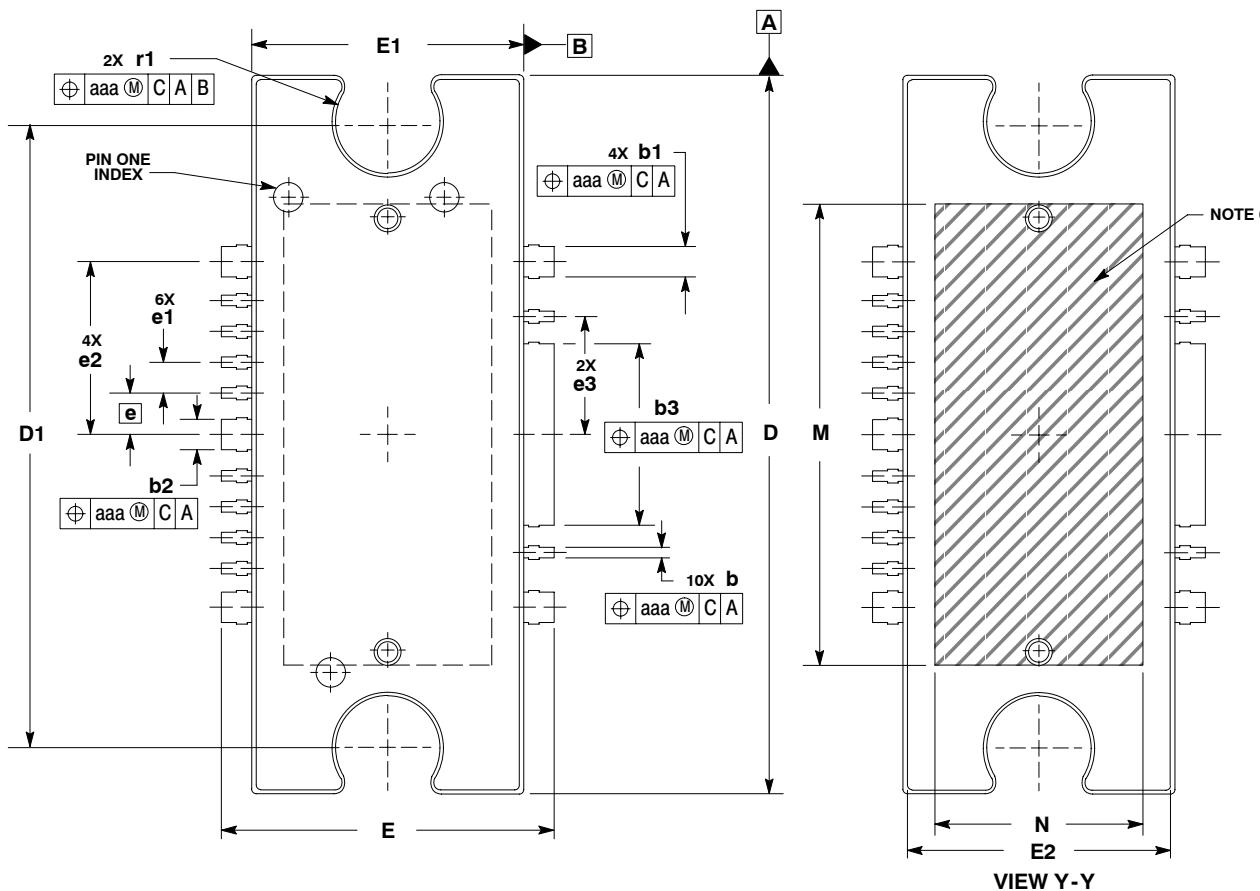
1. CONTROLLING DIMENSION: INCH.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
3. DATUM PLANE -H- IS LOCATED AT TOP OF LEAD AND IS COINCIDENT WITH THE LEAD WHERE THE LEAD EXITS THE PLASTIC BODY AT THE TOP OF THE PARTING LINE.
4. DIMENSIONS "D" AND "E1" DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS .006 (0.15) PER SIDE. DIMENSIONS "D" AND "E1" DO INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE -H-.
5. DIMENSIONS "b", "b1", "b2" AND "b3" DO NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE .005 (0.13) TOTAL IN EXCESS OF THE "b", "b1", "b2" AND "b3" DIMENSIONS AT MAXIMUM MATERIAL CONDITION.
6. HATCHING REPRESENTS THE EXPOSED AREA OF THE HEAT SLUG.
7. DIM A2 APPLIES WITHIN ZONE "J" ONLY.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.100	.104	2.54	2.64
A1	.038	.044	0.96	1.12
A2	.040	.042	1.02	1.07
D	.928	.932	23.57	23.67
D1	.810 BSC		20.57 BSC	
E	.551	.559	14.00	14.20
E1	.353	.357	8.97	9.07
E2	.346	.350	8.79	8.89
F	.025 BSC		0.64 BSC	
M	.600	---	15.24	---
N	.270	---	6.86	---
b	.011	.017	0.28	0.43
b1	.037	.043	0.94	1.09
b2	.037	.043	0.94	1.09
b3	.225	.231	5.72	5.87
c1	.007	.011	.18	.28
e	.054 BSC		1.37 BSC	
e1	.040 BSC		1.02 BSC	
e2	.224 BSC		5.69 BSC	
e3	.150 BSC		3.81 BSC	
r1	.063	.068	1.6	1.73
aaa	.004		.10	

**CASE 1329-09
ISSUE J
TO-272 WB-16
PLASTIC
MW4IC2230NBR1(MBR1)**

MW4IC2230NBR1 MW4IC2230GNBR1 MW4IC2230MBR1 MW4IC2230GMBR1

RF Device Data
Freescale Semiconductor



NOTES:

1. CONTROLLING DIMENSION: INCH.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
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5. DIMENSIONS "b", "b1", "b2" AND "b3" DO NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE .005 (0.13) TOTAL IN EXCESS OF THE "b", "b1", "b2" AND "b3" DIMENSIONS AT MAXIMUM MATERIAL CONDITION.
6. HATCHING REPRESENTS THE EXPOSED AREA OF THE HEAT SINK.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.100	.104	2.54	2.64
A1	.001	.004	0.02	0.10
A2	.099	.110	2.51	2.79
D	.928	.932	23.57	23.67
D1	.810 BSC		20.57 BSC	
E	.429	.437	10.90	11.10
E1	.353	.357	8.97	9.07
E2	.346	.350	8.79	8.89
L	.018	.024	4.90	5.06
L1	.01 BSC		0.25 BSC	
M	.600	---	15.24	---
N	.270	---	6.86	---
b	.011	.017	0.28	0.43
b1	.037	.043	0.94	1.09
b2	.037	.043	0.94	1.09
b3	.225	.231	5.72	5.87
c1	.007	.011	.18	.28
e	.054 BSC		1.37 BSC	
e1	.040 BSC		1.02 BSC	
e2	.224 BSC		5.69 BSC	
e3	.150 BSC		3.81 BSC	
r1	.063	.068	1.6	1.73
t	2°	8°	2°	8°
aaa	.004			.10

**CASE 1329A-03
ISSUE B
TO-272 WB-16 GULL
PLASTIC
MW4IC2230GNBR1(GMBR1)**

MW4IC2230NBR1 MW4IC2230GNBR1 MW4IC2230MBR1 MW4IC2230GMBR1

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